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[Vishay Semiconductor/Diodes Division](#)
[VS-STPS20L15GTRLP](#)

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sales@integrated-circuit.com



www.vishay.com

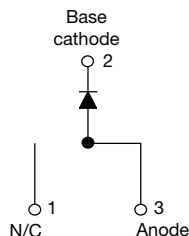
VS-STPS20L15GPbF

Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



TO-263AB (D²PAK)



FEATURES

- 125 °C T_J operation ($V_R < 5$ V)
- Center tap module
- Optimized for OR-ing applications
- Ultralow forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

PRODUCT SUMMARY

$I_{F(AV)}$	20 A
V_R	15 V
V_F at I_F	0.33 V
I_{RM} max.	600 mA at 100 °C
T_J max.	125 °C
E_{AS}	10 mJ
Package	TO-263AB (D ² PAK)
Diode variation	Single die

DESCRIPTION

The Schottky rectifier module has been optimized for ultralow forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	20	A
V_{RRM}		15	V
I_{FSM}	$t_p = 5 \mu s$ sine	700	A
V_F	19 A _{pk} , $T_J = 125$ °C (typical)	0.25	V
T_J	Range	-55 to +125	°C

VOLTAGE RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VS-STPS20L15GPbF	UNITS
Maximum DC reverse voltage	V_R	$T_J = 100$ °C	15	V
Maximum working peak reverse voltage	V_{RWM}			

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current See fig. 5	$I_{F(AV)}$	50 % duty cycle at $T_C = 85$ °C, rectangular waveform	20	A
Maximum peak one cycle non-repetitive surge current See fig. 7	I_{FSM}	5 μs sine or 3 μs rect. pulse	700	
		10 ms sine or 6 ms rect. pulse	330	
Non-repetitive avalanche energy	E_{AS}	$T_J = 25$ °C, $I_{AS} = 2$ A, $L = 6$ mH	10	mJ
Repetitive avalanche current	I_{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical	2	A



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Forward voltage drop See fig. 1	$V_{FM}^{(1)}$	19 A	$T_J = 25\text{ }^{\circ}\text{C}$	-	0.41	V
		40 A		-	0.52	
		19 A	$T_J = 125\text{ }^{\circ}\text{C}$	0.25	0.33	
		40 A		0.37	0.50	
Reverse leakage current See fig. 2	$I_{RM}^{(1)}$	$T_J = 25\text{ }^{\circ}\text{C}$	$V_R = \text{Rated } V_R$	-	10	mA
		$T_J = 100\text{ }^{\circ}\text{C}$		-	600	
Threshold voltage	$V_{F(TO)}$	$T_J = T_J \text{ maximum}$		0.182		V
Forward slope resistance	r_t			7.6		mW
Maximum junction capacitance	C_T	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^{\circ}\text{C}$		-	2000	pF
Typical series inductance	L_S	Measured lead to lead 5 mm from package body		8	-	nH
Maximum voltage rate of change	dV/dt	Rated V_R		10 000		V/ μ s

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J		-55 to +125	°C
Maximum storage temperature range	T _{Stg}		-55 to +150	
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.5	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased (for TO-220)	0.50	
Maximum thermal resistance, junction to ambient	R _{thJA}	DC operation (for D ² PAK)	40	
Approximate weight			2	g
			0.07	oz.
Mounting torque	minimum	Non-lubricated threads	6 (5)	kgf · cm (lbf · in)
	maximum		12 (10)	
Marking device		Case style D ² PAK	STPS20L15G	



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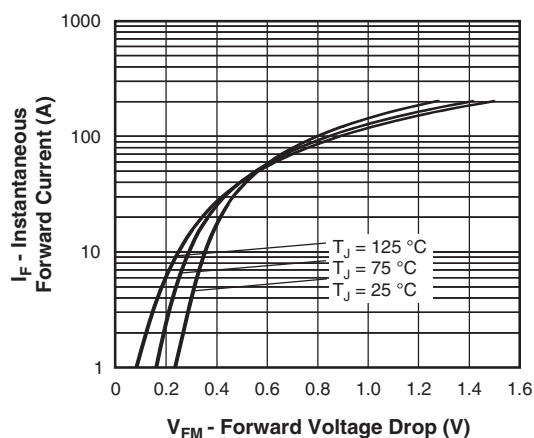


Fig. 1 - Maximum Forward Voltage Drop Characteristics

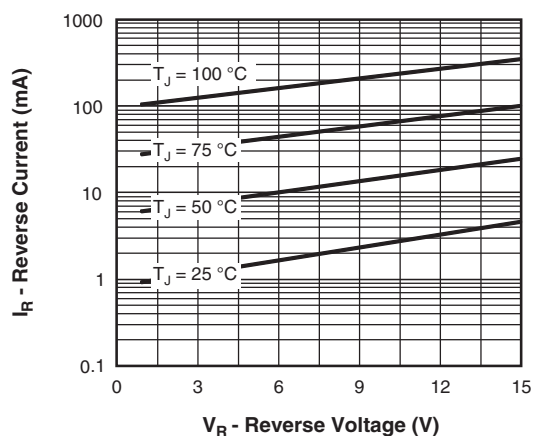


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

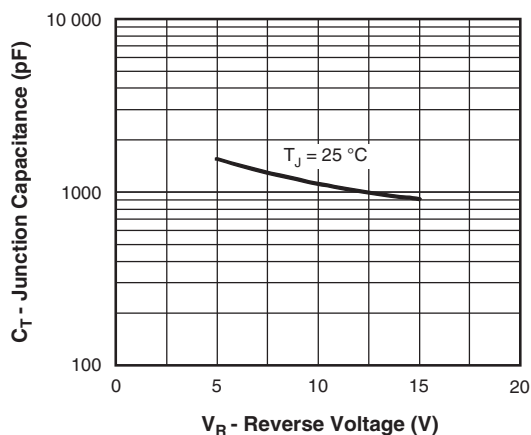


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

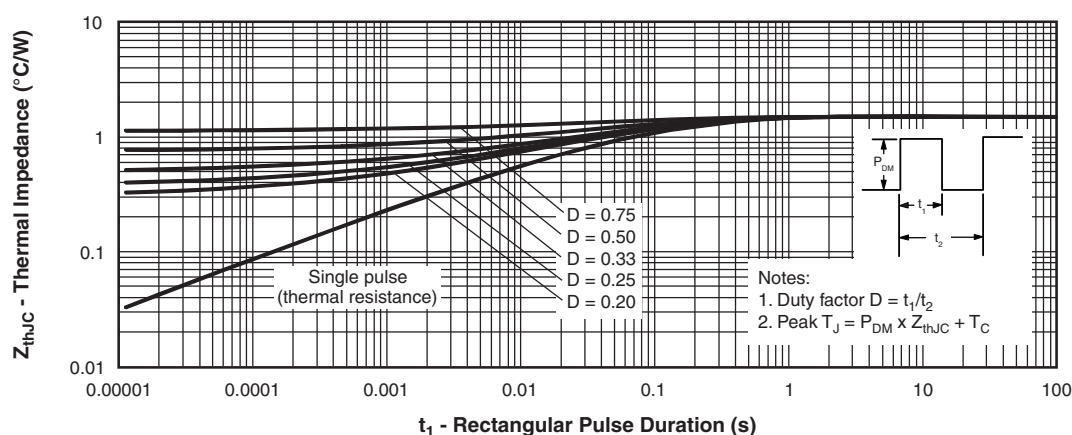


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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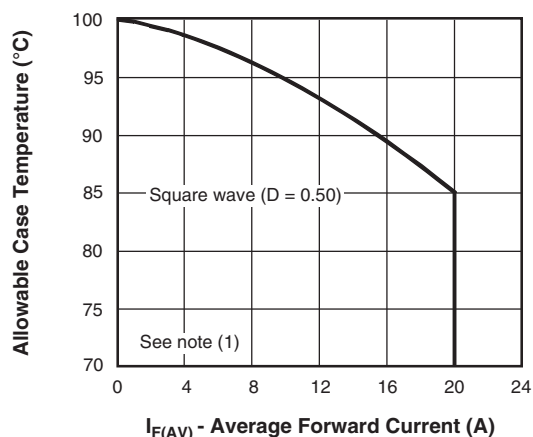


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

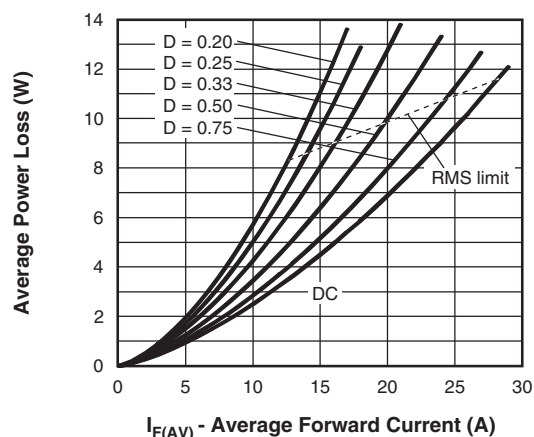


Fig. 6 - Forward Power Loss Characteristics

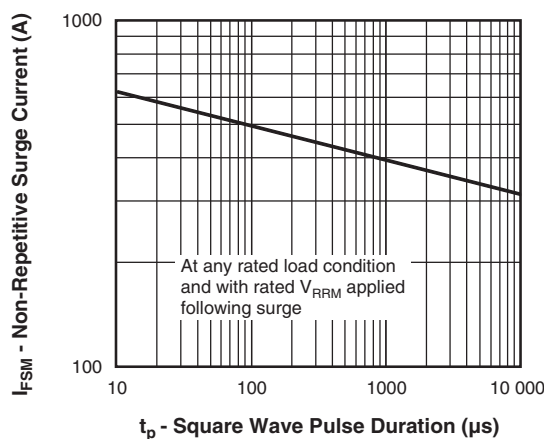


Fig. 7 - Maximum Non-Repetitive Surge Current

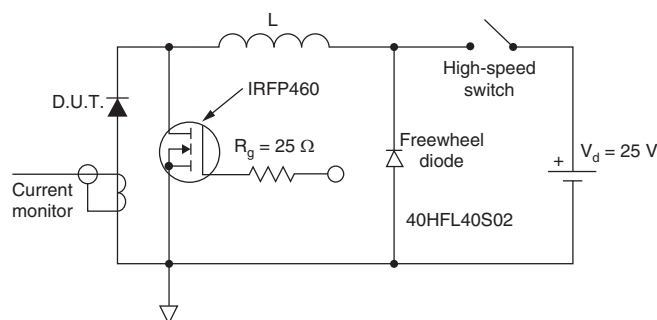


Fig. 8 - Unclamped Inductive Test Circuit

Note

- (1) Formula used: $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$;
 P_d = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);
 P_{dREV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80\%$ rated V_R



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ORDERING INFORMATION TABLE

Device code	VS-	STPS	20	L	15	G	TRL	PbF
	1	2	3	4	5	6	7	8

- | | |
|---|---|
| 1 | - Vishay Semiconductors product |
| 2 | - Essential part number |
| 3 | - Current rating (20 = 20 A) |
| 4 | - Low voltage |
| 5 | - Voltage rating (15 = 15 V) |
| 6 | - G = D ² PAK package |
| 7 | - <ul style="list-style-type: none"> • None = tube • TRL = tape and reel (left oriented) • TRR = tape and reel (right oriented) |
| 8 | - <ul style="list-style-type: none"> • PbF = lead (Pb)-free (for D²PAK tube) • P = lead (Pb)-free (for D²PAK TRR and TRL) |

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-STPS20L15GPbF	50	1000	Antistatic plastic tubes
VS-STPS20L15GTRLP	800	800	13" diameter reel
VS-STPS20L15GTTRP	800	800	13" diameter reel

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95046
Part marking information	www.vishay.com/doc?95054
Packaging information	www.vishay.com/doc?95032



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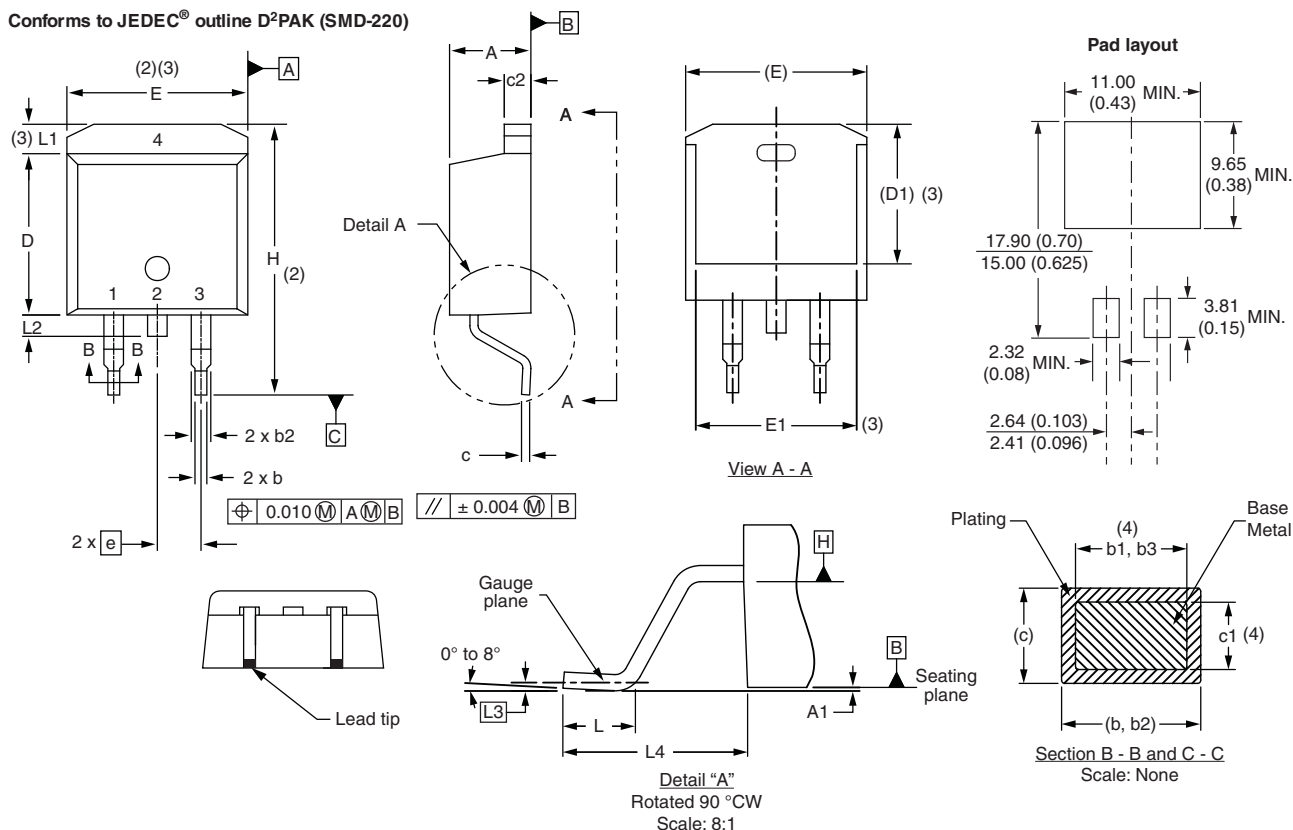
Outline Dimensions

Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches

Conforms to JEDEC® outline D²PAK (SMD-220)



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
c	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
e	2.54 BSC		0.100 BSC		
H	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010 BSC		
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC® outline TO-263AB



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